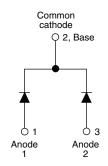


HEXFRED® Ultrafast Soft Recovery Diode, 2 x 6 A



TO-247AC 3L



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 6 A				
V_R	1200 V				
V _F at I _F	2.4 V				
t _{rr} typ.	26 ns				
T _J max.	150 °C				
Package	TO-247AC 3L				
Circuit configuration	Common cathode				

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RBM} and Q_{rr}
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ROHS COMPLIANT HALOGEN FREE

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- · Higher frequency operation
- · Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA12PA120C... is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. The VS-HFA12PA120C... has basic ratings of 1200 V and 6 A per leg continuous current. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA12PA120C... is ideally suited for applications in power supplies and power conversion systems (such as inverters, converters, UPS systems, and power factor correction circuits), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V_R		1200	V		
Maximum continuous forward current per leg	_	T _C = 100 °C	6	A		
per device	· I _F		12			
Single pulse forward current	I _{FSM}	t _p = 10 ms	80	A		
Maximum repetitive forward current	I _{FRM}		24			
Maximum navay discination	P _D	T _C = 25 °C	62.5	W		
Maximum power dissipation		T _C = 100 °C	25] vv		
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C		

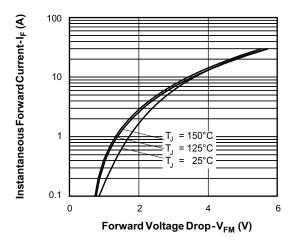




ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V _{BR}	Ι _R = 100 μΑ	1200	-	-		
	V _{FM}	I _F = 6 A	-	2.7	3.0	V	
Maximum forward voltage		I _F = 12 A	-	3.5	3.9		
		I _F = 6 A, T _J = 125 °C	-	2.4	2.8		
Maximum reverse		$V_R = V_R$ rated	-	0.26	5.0		
leakage current	I _{RM}	T _J = 125 °C, V _R = 0.8 x V _R rated	-	110	500	μA	
Junction capacitance	C _T	V _R = 200 V	-	9.0	14	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	=.	nH	

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200$	$A/\mu s$, $V_R = 30 V$	-	26	-	ns	
Reverse recovery time	t _{rr1}	T _J = 25 °C	I _F = 6 A dI _F /dt = 200 A/μs V _R = 200 V	-	53	80		
	t _{rr2}	T _J = 125 °C		-	87	130		
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	4.4	8.0	A nC A/μs	
reak recovery current	I _{RRM2}	T _J = 125 °C		-	5.0	9.0		
Dovorco rocovery charge	Q _{rr1}	T _J = 25 °C		-	116	320		
Reverse recovery charge	Q _{rr2}	T _J = 125 °C		-	233	585		
Peak rate of fall of recovery current during t _b	dI _{(rec)M} /dt1	T _J = 25 °C		-	180	i		
	dI _{(rec)M} /dt2	T _J = 125 °C		-	100	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	L TEST CONDITIONS		TYP.	MAX.	UNITS	
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	2.0		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	K/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.50	-		
Weight			-	2.0	-	g	
vveigni			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-247AC 3L	HFA12PA120C				





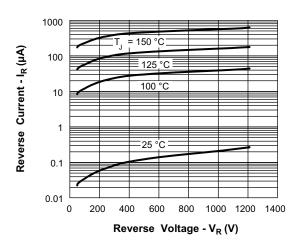


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

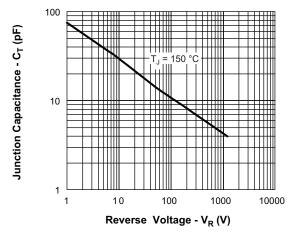


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

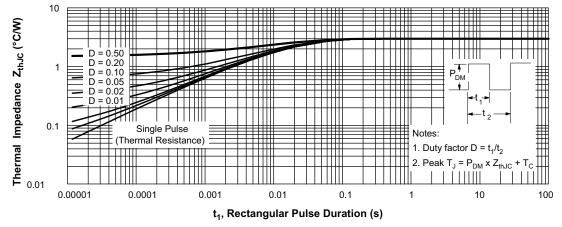


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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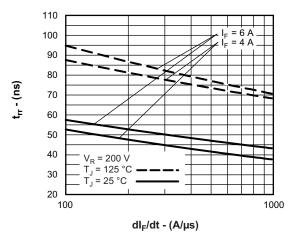


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

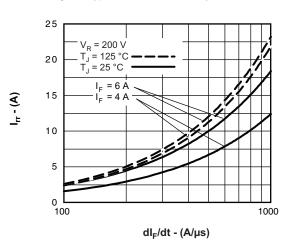


Fig. 6 - Typical Recovery Current vs. dl_F/dt

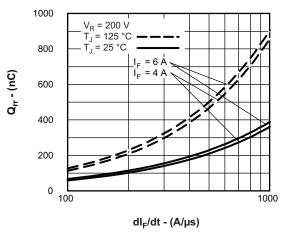


Fig. 7 - Typical Stored Charge vs. dl_F/dt

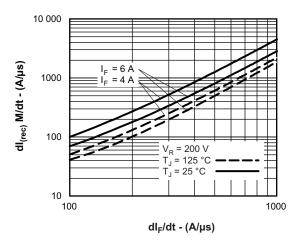
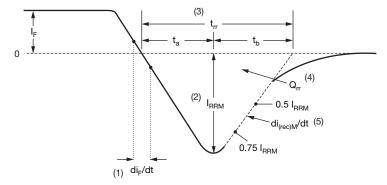


Fig. 8 - Typical dl_{(rec)M}/dt vs. dl_F/dt



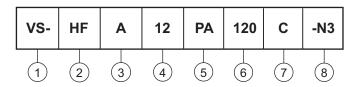
- di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_F$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$
 - $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (5) $di_{(rec)M}/dt$ peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - HEXFRED® family

3 - Electron irradiated

Current rating (12 = 12 A)

5 - PA = TO-247AC, 3 pins

- Voltage rating: (120 = 1200 V)

Circuit configuration

C = common cathode

8 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

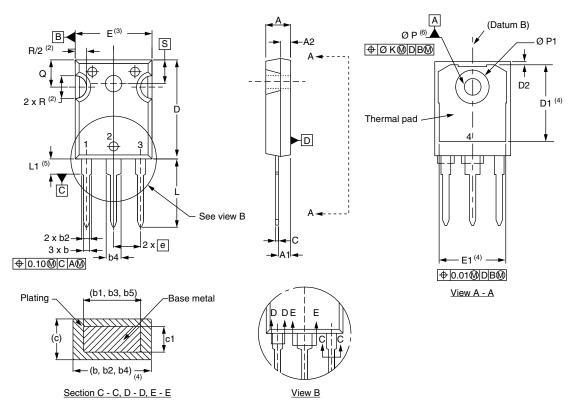
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-HFA12PA120C-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96138</u>				
Part marking information	www.vishay.com/doc?95007			



TO-247AC 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES
STINIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	MILLIMETERS INCHES		HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	254	0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC 0.217 BS		BSC		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension Q



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